

CHEMICAL KINETICS

EDITED BY

C.H. BAMFORD

M.A., Ph.D., Sc.D. (Cantab.), F.R.I.C., F.R.S.
*Formerly Campbell-Brown Professor of Industrial Chemistry,
University of Liverpool*

The late C.F.H. TIPPER

Ph.D. (Bristol), D.Sc. (Edinburgh)
*Senior Lecturer in Physical Chemistry,
University of Liverpool*

AND

R.G. COMPTON

M.A., D.Phil. (Oxon.)
*Lecturer in Physical Chemistry,
University of Liverpool*

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Contents

Preface	ix
<i>Chapter 1 (A.T. Fromhold, Jr. and R.G. Fromhold)</i>	
An overview of metal oxidation theory	1
1. An introduction to the fundamental concepts.	1
1.1 Stages of oxide formation.	1
1.2 Interfacial reactions and concentration differences.	5
1.3 Role of electrons and electron holes	8
1.4 Charge conservation.	10
1.5 Electric forces.	15
1.6 Electric fields	17
1.7 Electrical energy	18
1.8 Planar charge distributions	19
1.9 Electrostatic potentials and voltages	22
1.10 Concentration and electrochemical potential gradients as driving forces for particle currents and oxide growth	28
1.11 Microscopic hopping transport.	36
1.12 Effects of space charge on the currents	53
1.13 Growth by uncharged particle transport.	64
1.14 Single current theories	66
1.14.1 Cabrera—Mott approach to thermal oxidation	66
1.14.2 Anodic oxidation under constant voltage conditions.	68
1.14.3 Anodic oxidation under constant current conditions.	69
1.15 Coupled-currents approach to thermal oxidation.	69
1.16 The thick-film parabolic growth law	72
2. Multilayer oxides.	79
2.1 Background	79
2.2 The case of oxide growth by diffusion of cation interstitials and electrons	82
2.3 The case of oxide growth by diffusion of cation vacancies and electron holes.	90
2.4 The case of oxide growth by diffusion of anion interstitials and electron holes.	97
2.5 The case of oxide growth by diffusion of anion vacancies and electrons	103
2.6 Comparison of the sets of final equations deduced above for the four cases.	111
2.7 General matrix form for the growth equations valid for any specific mobile defect species	114
Conclusion.	115
Acknowledgements	115
References	116

Chapter 2 (Y. Koga and L.G. Harrison)

Reactions of solids with gases other than oxygen	119
1. Introduction	119
2. Gaseous reduction of solids	120
2.1 Kinetics	120
2.2 Structural change on reduction. Ordering of defects	131
3. Effects of hydrogen on metals	133
3.1 Solution of hydrogen in metals	133
3.2 Hydrogen embrittlement of metals	135
4. Reactions of solids with halogens	137
4.1 Isotopic exchange reactions	137
4.2 Chemical reactions. Electron transfer and electronic defects	139
5. Direct determination of the activities of reacting species at the inter- face	140
6. Reaction of atmospheric pollutants with calcite and marble	144
References	146

Chapter 3 (D. Brennan)

Heterogeneous atomisation and recombination	151
1. Introduction	151
2. General theory of atomisation and recombination	152
2.1 Desorption mechanisms	152
2.1.1 A model for the adsorbed state	152
2.1.2 Desorption of atoms	154
2.1.3 Frequency of collision between adatoms	154
2.1.4 Desorption of molecules	159
2.1.5 Conditions for a negligible rate of molecular desorption relative to the rate of atomic desorption	160
2.2 Atomisation kinetics	161
2.2.1 Significant processes at the surface	161
2.2.2 Application of the principle of microscopic reversibility	163
2.2.3 Kinetics of atomisation under stationary conditions when molecular adsorption is unactivated	164
2.2.4 Atomisation kinetics when molecular adsorption is activated	169
2.3 Recombination reactions	170
2.3.1 Mechanisms of recombination	170
2.3.2 Recombination in the absence of atomic desorption	173
2.3.3 Recombination in the presence of atomic desorption	178
3. Experimental methods and results. Atomisation	180
3.1 Energy loss method	180
3.2 Methods based on the trapping of atoms	181
3.2.1 Experiments with static systems	182
3.2.2 Flow system experiments	190
3.2.3 The absence of trapping of thermally excited molecules	194
3.3 Mass spectrometric methods	196
4. Experimental methods and results. Recombination	200
4.1 Experimental methods	200
4.1.1 Side arm method. Steady state static system	200
4.1.2 Steady state flow systems	205
4.1.3 Non-steady state methods	207
4.1.4 Effusion method	209
4.2 Selected results	210

4.2.1 The diffusion coefficient	210
4.2.2 Energy accommodation during heterogeneous recombination. .	211
4.2.3 Recombination of H atoms on glass and silica	219
4.2.4 Recombination of H atoms on metals	224
4.2.5 Recombination of O atoms on metals and oxides.	226
Symbols	227
References	231
Index	235